



Data Sheet

N-CHANNEL 500V - 0.31W - 14A PowerMesh II MOSFET

Manufacturers <u>STMicroelectronics</u>, Inc

Package/Case TO-247

Product Type Transistors

**RoHS** 

Lifecycle

**Features** 



Images are for reference only

Please submit RFQ for STW14NC50 or Email to us: sales@ovaga.com We will contact you in 12 hours.

**RFO** 

## **General Description**

STW14NC50 is a type of power MOSFET (Metal Oxide Semiconductor Field Effect Transistor) manufactured by STMicroelectronics.

It has a maximum drain-source voltage (Vds) of 500V.

It can handle a maximum continuous drain current (Id) of 14A.

It has a low on-resistance (Rds(on)) of 0.4 Ohm, which means it has a low voltage drop across the transistor when it is conducting current.

It is designed for high-speed switching applications.

It has a TO-247 package, which allows for high thermal conductivity and high power dissipation.

## **Application**

Switching power supplies.

Motor control.

Lighting ballasts.

Welding equipment.

UPS (Uninterruptible Power

Supplies) systems.



## **Related Products**



STF42N65M5
STMicroelectronics, Inc

TO-220FP



STP11NM60FD STMicroelectronics, Inc TO-220



STB75NF75
STMicroelectronics, Inc
TO-263



STN9360 STMicroelectronics, Inc SOT-223



STN3NF06 STMicroelectronics, Inc SOT-223



STP11NK50Z STMicroelectronics, Inc TO-220-3



STN951 STMicroelectronics, Inc SOT-223



STN83003 STMicroelectronics, Inc SOT-223